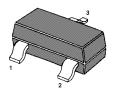
NPN Silicon Epitaxial Planar Transistor

for switching and amplifier applications.

As complementary type the PNP transistor MMBT8550 is recommended.



1.BASE 2.EMITTER 3.COLLECTOR TO-236 Plastic Package

Absolute Maximum Ratings (T_a = 25 °C)

| Parameter | Symbol | Value | Unit |
|---------------------------|------------------|---------------------|------|
| Collector Base Voltage | V_{CBO} | V _{CBO} 40 | |
| Collector Emitter Voltage | V_{CEO} | 25 | V |
| Emitter Base Voltage | V_{EBO} | 6 | V |
| Collector Current | I _C | 600 | mA |
| Power Dissipation | P _{tot} | 350 | mW |
| Junction Temperature | T _j | 150 | °C |
| Storage Temperature Range | T _{Stg} | - 55 to + 150 | °C |

Characteristics at Ta = 25 °C

| Characteristics at I _a = 25 °C | | | | | | |
|---|-----------|------------------|------|------|------|--------|
| Parameter | | Symbol | Min. | Тур. | Max. | Unit |
| DC Current Gain | | | | | | |
| at $V_{CE} = 1 \text{ V}, I_{C} = 100 \text{ mA}$ | 1MBT8050C | h_{FE} | 100 | - | 250 | - |
| N | MBT8050D | h_{FE} | 160 | - | 400 | - |
| at $V_{CE} = 1 \text{ V}, I_{C} = 500 \text{ mA}$ | | h_{FE} | 40 | - | - | - |
| Collector Base Cutoff Current | | | | | 100 | n 1 |
| at V _{CB} = 35 V | | I _{CBO} | - | - | 100 | nA |
| Collector Base Breakdown Voltage | | V | 40 | | | V |
| at $I_C = 10 \mu A$ | | $V_{(BR)CBO}$ | 40 | - | - | V |
| Collector Emitter Breakdown Voltage | | V | 25 | | | V |
| at $I_C = 2 \text{ mA}$ | | $V_{(BR)CEO}$ | 25 | - | - | V |
| Emitter Base Breakdown Voltage | | V | 6 | | | V |
| at I _E = 100 μA | | $V_{(BR)EBO}$ | О | - | - | V |
| Collector Emitter Saturation Voltage | | \/ | | | 0.5 | V |
| at $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$ | | $V_{CE(sat)}$ | - | - | 0.5 | V |
| Base Emitter Saturation Voltage | | \/ | | | 1.2 | V |
| at $I_C = 500 \text{ mA}$, $I_B = 50 \text{ mA}$ | | $V_{BE(sat)}$ | - | - | 1.2 | V |
| Gain Bandwidth Product | | £ | | 100 | | N/ILI- |
| at $V_{CE} = 5 \text{ V}$, $I_C = 10 \text{ mA}$ | | f _T | - | 100 | - | MHz |



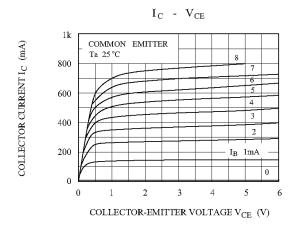


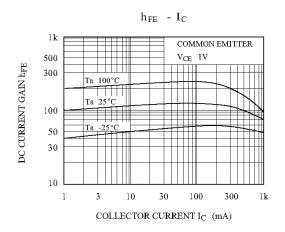


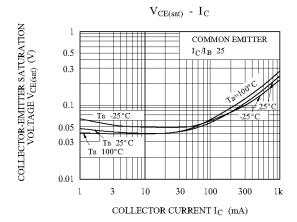


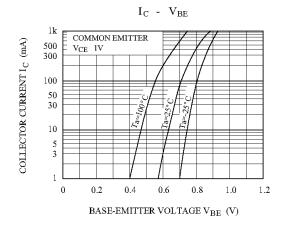


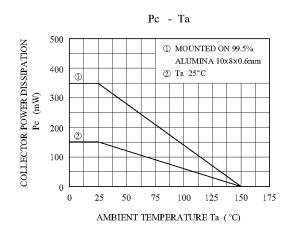
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